



**Product data sheet** 

## 1. Product profile

## 1.1 General description

PNP switching transistor in a SOT23 (TO-236AB) small Surface-Mounted Device (SMD) plastic package.

NPN complement: PMBT3904.

## **1.2 Features and benefits**

- Collector-emitter voltage V<sub>CEO</sub> = -40 V
- Collector current capability I<sub>C</sub> = -200 mA

### **1.3 Applications**

General amplification and switching

## 1.4 Quick reference data

Table 1.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	-40	V
I <sub>C</sub>	collector current		-	-	-200	mA

## 2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	base		
2	emitter		3
3	collector		
			006aab25



## 3. Ordering information

Table 3. Order	ring informa	ition	
Type number	Package		
	Name	Description	Version
PMBT3906	-	plastic surface-mounted package; 3 leads	SOT23

## 4. Marking

#### Table 4.Marking codes

Type number	Marking code <sup>[1]</sup>
PMBT3906	*2A

- [1] \* = -: made in Hong Kong
  - \* = p: made in Hong Kong
  - \* = t: made in Malaysia
  - \* = W: made in China

## 5. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		0,	,		
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-40	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-40	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	-6	V
I <sub>C</sub>	collector current		-	-200	mA
I <sub>CM</sub>	peak collector current		-	-200	mA
I <sub>BM</sub>	peak base current		-	-100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u> -	250	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB).

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**PNP** switching transistor

# 6. Thermal characteristics

Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	500	K/W

[1] Device mounted on an FR4 PCB.

# 7. Characteristics

#### Table 7.Characteristics

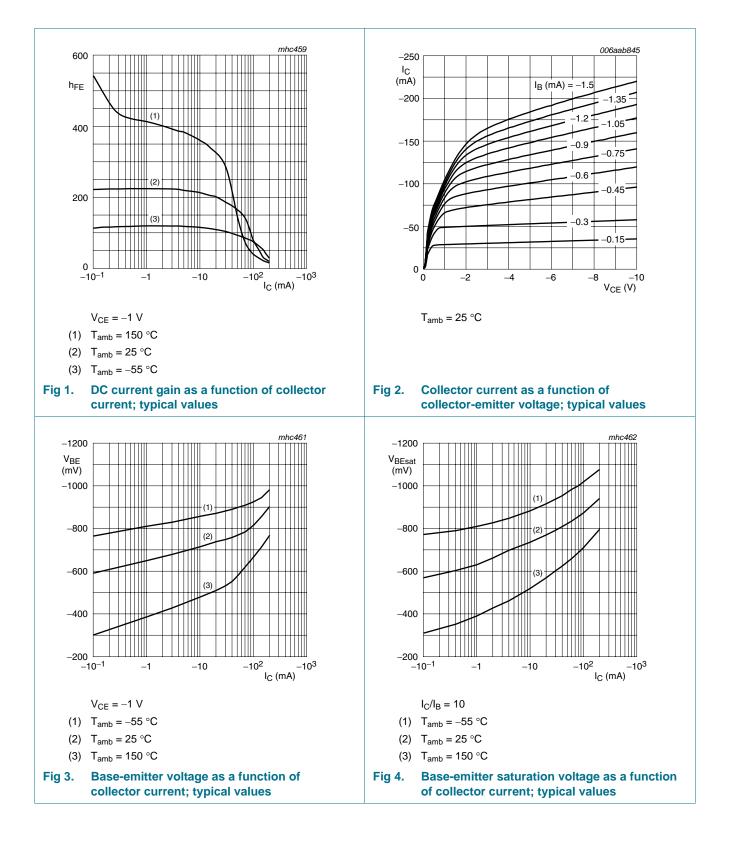
 $T_{amb} = 25 \ ^{\circ}C$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}$	-	-	-50	nA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -6 V; I_C = 0 A$	-	-	-50	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = -1 V$				
		$I_{\rm C} = -0.1  {\rm mA}$	60	-	-	
		$I_{\rm C} = -1  \rm{mA}$	80	-	-	
		I <sub>C</sub> = -10 mA	100	-	300	
		I <sub>C</sub> = -50 mA	60	-	-	
		I <sub>C</sub> = -100 mA	30	-	-	
V <sub>CEsat</sub> collector-emitter saturation voltage		$I_{C} = -10 \text{ mA}; I_{B} = -1 \text{ mA}$	-	-	-250	mV
	saturation voltage	$I_{C} = -50 \text{ mA}; I_{B} = -5 \text{ mA}$	-	-	-400	mV
DEGU	base-emitter	$I_{C} = -10 \text{ mA}; I_{B} = -1 \text{ mA}$	-	-	-850	mV
	saturation voltage	$I_{\rm C} = -50$ mA; $I_{\rm B} = -5$ mA	-	-	-950	mV
t <sub>d</sub>	delay time	$I_{Con} = -10 \text{ mA};$	-	-	35	ns
t <sub>r</sub>	rise time	$I_{Bon} = -1 \text{ mA};$	-	-	35	ns
t <sub>on</sub>	turn-on time	I <sub>Boff</sub> = 1 mA	-	-	70	ns
t <sub>s</sub>	storage time		-	-	225	ns
t <sub>f</sub>	fall time		-	-	75	ns
t <sub>off</sub>	turn-off time		-	-	300	ns
f <sub>T</sub>	transition frequency	$V_{CE} = -20 \text{ V};$ $I_{C} = -10 \text{ mA};$ f = 100 MHz	250	-	-	MHz
Cc	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB} = -5 \ V; \ I_E = i_e = 0 \ A; \\ f = 1 \ MHz \end{array}$	-	-	4.5	pF
C <sub>e</sub>	emitter capacitance	$V_{EB} = -500 \text{ mV};$ $I_{C} = i_{c} = 0 \text{ A}; \text{ f} = 1 \text{ MHz}$	-	-	10	pF
NF	noise figure	$I_{C} = -100 \ \mu A;$ $V_{CE} = -5 \ V; R_{S} = 1 \ k\Omega;$ f = 10 Hz to 15.7 kHz	-	-	4	dB

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# **PMBT3906**

### **PNP** switching transistor

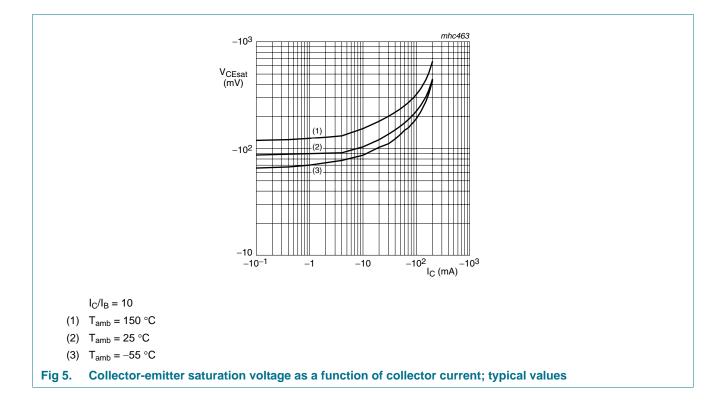


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### **PNP** switching transistor

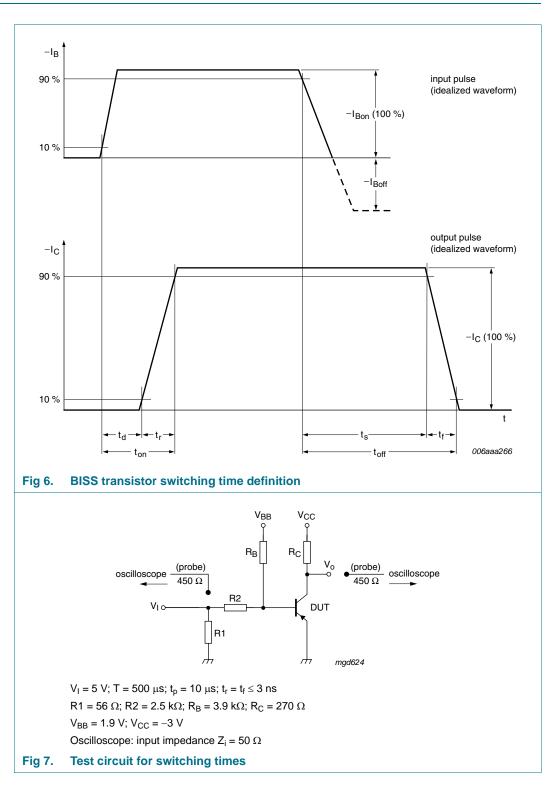


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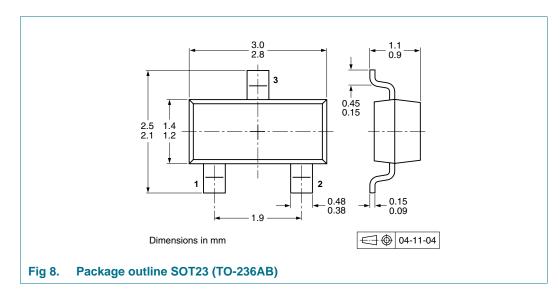
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# 8. Test information



**PNP** switching transistor

## 9. Package outline



# **10. Packing information**

#### Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	
			3000	10000
PMBT3906	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235

[1] For further information and the availability of packing methods, see <u>Section 13</u>.

# **11. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes		
PMBT3906_6	20100302	Product data sheet	-	PMBT3906_N_5		
Modifications:		of this data sheet has beer of NXP Semiconductors.	n redesigned to comply w	with the new identity		
	<ul> <li>Legal texts</li> </ul>	have been adapted to the r	new company name whe	ere appropriate.		
	<ul> <li>Section 4 "Marking": amended</li> </ul>					
	<ul> <li>Table 7 "Characteristics": F redefined to NF noise figure</li> </ul>					
	Section 8 "Test information": added					
	• Figure 6: added					
	<ul> <li>Figure 8: superseded by minimized package outline drawing</li> </ul>					
	<ul> <li>Section 10 "Packing information": added</li> </ul>					
	Section 12	"Legal information": update	d			
PMBT3906_N_5	20071004	Product data sheet	-	PMBT3906_4		
PMBT3906_4	20040121	Product specification	-	PMBT3906_3		
PMBT3906_3	19990427	Product specification	-	PMBT3906_CNV_2		
PMBT3906 CNV 2	19970505	Product specification	-	-		

## 12. Legal information

## 12.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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For sales office addresses, please send an email to: <a href="mailto:salesaddresses@nxp.com">salesaddresses@nxp.com</a>

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